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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/633,709	08/05/2003	Soo-Geun Lee	259/021	6770	
7590 05/28/2004			EXAMINER		
LEE & STERBA, P.C.			PHAM, LONG		
Suite 2000 1101 Wilson Boulevard			ART UNIT	PAPER NUMBER	
Arlington, DC 22209			2814		
			DATE MAILED: 05/28/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicat	ion No.	Applicant(s)				
Office Action Summary		10/633,7	709	LEE ET AL.				
		Examine	er	Art Unit				
		Long Ph	am	2814				
 Period for	The MAILING DATE of this c mmur Reply	nication appears n th	e cover sheet with the	e correspondence add	iress			
THE M - Extens after S - If the p - If NO p - Failure Any re	RTENED STATUTORY PERIOD F IAILING DATE OF THIS COMMUN ions of time may be available under the provisions IX (6) MONTHS from the mailing date of this commerciod for reply specified above is less than thirty (3 beriod for reply is specified above, the maximum stato reply within the set or extended period for reply ply received by the Office later than three months I patent term adjustment. See 37 CFR 1.704(b).	ICATION. s of 37 CFR 1.136(a). In no e munication. 30) days, a reply within the statutory period will apply and y will, by statute, cause the ap	vent, however, may a reply be atutory minimum of thirty (30) will expire SIX (6) MONTHS fr plication to become ABANDO	e timely filed days will be considered timely, om the mailing date of this cor NED (35 U.S.C. § 133).	nmunication.			
Status								
1) 🗌 F	Responsive to communication(s) file	ed on						
2a)□ ☐								
3) 🗌 💲								
C	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.							
Dispositio	on of Claims							
4)🛛 (☑ Claim(s) <u>1-33</u> is/are pending in the application.							
4	4a) Of the above claim(s) 15-26 is/are withdrawn from consideration.							
5)🛛 (⊠ Claim(s) <u>1-14</u> is/are allowed.							
6)⊠ (⊠ Claim(s) <u>27-33</u> is/are rejected.							
7) 🗌 (Claim(s) is/are objected to.							
8) 🗌 (Claim(s) are subject to restriction and/or election requirement.							
Application	on Papers							
9) The specification is objected to by the Examiner.								
10)⊠ T	10)⊠ The drawing(s) filed on <u>08/05/03</u> is/are: a) accepted or b) objected to by the Examiner.							
,	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
F	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)∐ T	11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority u	nder 35 U.S.C. § 119							
a)[Acknowledgment is made of a claim All b) Some * c) None of: 1. Certified copies of the priority 2. Certified copies of the priority 3. Copies of the certified copies application from the Internationse the attached detailed Office actions	documents have be documents have be of the priority documents Bureau (PCT Ru	en received. en received in Applic nents have been rece ule 17.2(a)).	ation No ived in this National S	Stage			
Attachment(• •		∆ □ 1-1	on/(DTO 442)				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)			4) Interview Summ Paper No(s)/Mai					
3) 🛛 Inform	ation Disclosure Statement(s) (PTO-1449 o No(s)/Mail Date 12/22/03.			al Patent Application (PTO	-152)			

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DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of claims 1-14 and 27-33 in Paper No. 03/12/04 is acknowledged.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claim 27 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al. (KR P2001-59316A) in combination with Ishimaru (US 20020037643).

With respect to claim 27, Lee et al. teaches an image sensor device, comprising:

a photodiode in a substrate 1;

an interlayer dielectric structure and light passageway which passes through the interlayer dielectric structure, the light passageway being positioned in alignment with the photodiode;

a transparent dielectric layer 16 which fills the light passageway;

a color filter 10 positioned over a light inlet of the light passageway; and

a lens 12 positioned over the color filter in alignment with the light passageway. See fig. 2d and the English abstract.

Lee et al. fail to teach that the interlayer dielectric structure is made of SiN or SiC or opaque material.

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Ishimaru teaches an interlayer dielectric structure made of SiN or SiC to suppress diffusion and corrosion of metal. See [0024].

It would have been obvious to one of <u>ordinary skill</u> in the art of making semiconductor devices to form the interlayer dielectric structure of SiN or SiC in the device of Lee et al. to obtain the above advantages. See [0024].

3. Claims 28, 29, 30, 31, 32, and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al. (KR P2001-59316A) in combination with Ishimaru (US 20020037643) as applied to claim 27 above, and further in view of Park et al. (US 20030100181).

With respect to claim 28, Lee et al. do not appear to teach that the transparent dielectric is made of photoresist.

However, it is well-known in the art that photoresist is transparent.

With respect to claim 29, Lee et al. fail to teach that the interlayer dielectric structure has a copper contact.

Park et al. teach an interlayer dielectric structure having a copper contact. See the abstract.

It would have been obvious to one of <u>ordinary skill</u> in the art of making semiconductor devices to include a copper contact in the interlayer dielectric structure of Lee et al. to provide electrical connection to other copper lines. See the abstract.

With respect to claim 30, Lee et al. further teach a first interlayer dielectric layer 5 between the substrate and the interlayer dielectric structure 7,9 to cover the photodiode 3 formed in the substrate. See fig. 2d
With respect to claims 31, 32, and 33, Lee et al. further teach a protection layer or barrier metal layer made of nitride or anti-reflection material. See the English abstract and fig. 2d.

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Allowable Subject Matter

4. Claims 1-14 are allowed.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Long Pham whose telephone number is 571-272-1714. The examiner can normally be reached on M-F, 7:30AM-3:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact—the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Long-Pham

Primary Examiner

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